



4.8mm Semi-Lens Silicon PIN Photodiode

MODEL NO : PD438B/L1

■ Features :

- Fast response time
- High photo sensitivity
- Small junction capacitance

■ Description :

- PD438B/L1 is a high speed and sensitive PIN photodiode in a cylindrical side view plastic package. The epoxy package itself is an IR filter, spectrally matched to GaAs or GaAlAs IR emitter.

■ Applications :

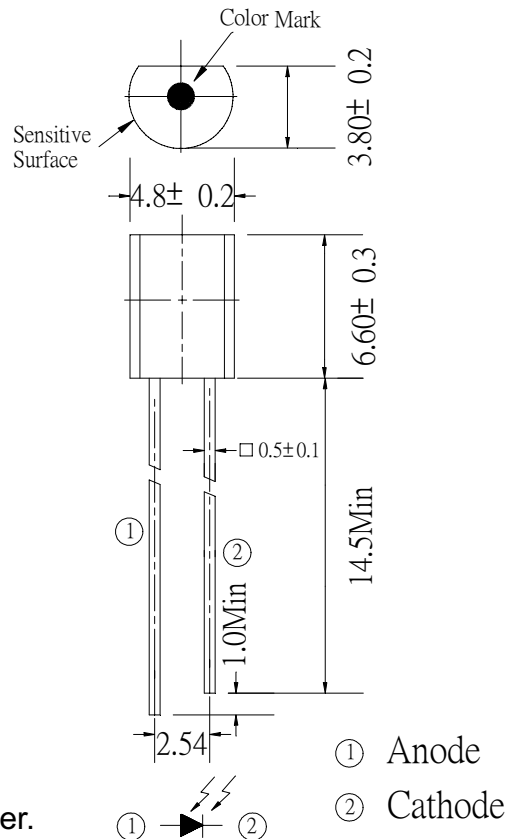
- High speed photo detector
- Camera
- Infrared remote controller for TVs VCR, audio equipment, air conditioner, etc.

PART NO.	CHIP	LENS COLOR
	MATERIAL	
PD	Silicon	Black

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■ Package Dimensions:



■ Notes :

1. All dimensions are in millimeter.
2. Protruded resin under flange 1.5 mm Max.
3. Lead spacing is measured where the lead emerge from the package.
4. Lens color : Black.
5. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
6. These specification sheets include materials protected under copyright of EVERLIGHT corporation . Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
7. When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.



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■ Absolute Maximum Ratings at $T_A = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit	Notice
Reverse Voltage	V_R	32	V	
Power Dissipation	P_d	150	mW	
Lead Soldering Temperature	T_{sol}	260	$^\circ\text{C}$	4mm from mold body less than 5 seconds
Operating Temperature	T_{opr}	-25 ~ +85	$^\circ\text{C}$	
Storage Temperature	T_{stg}	-40 ~ +85	$^\circ\text{C}$	

■ Electronic Optical Characteristics :

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Rang of Spectral Bandwidth	$\lambda_{0.5}$	----	840---1200	----	nm	----
Wavelength of Peak Sensitivity	λ_p	----	980	----	nm	----
Open-Circuit Voltage	V_{OC}	----	0.41	----	V	$E_e=5\text{mW}/\text{cm}^2$ $\lambda_p=940\text{nm}$
Short-Circuit Current	I_{SC}	----	30	----	μA	
Reverse Light Current	I_L	----	30	----	μA	$E_e=5\text{mW}/\text{cm}^2$ $\lambda_p=940\text{nm}$ $V_R=5\text{V}$
Dark Current	I_D	----	----	10	nA	$E_e=0\text{mW}/\text{cm}^2$ $V_R=10\text{V}$
Reverse Breakdown Voltage	B_{VR}	32	170	----	V	$E_e=0\text{mW}/\text{cm}^2$ $I_R=100\mu\text{A}$
Total Capacitance	C_t	----	6	----	pF	$E_e=0\text{mW}/\text{cm}^2$ $f=1\text{MHZ}$ $V_R=5\text{V}$
Rise/Fall Time	t_r/t_f	----	10/10	----	nS	$R_L=1000\Omega$ $V_R=10\text{V}$



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■ Typical Electrical/Optical/Characteristics Curves

Fig. 1 Power Dissipation vs. Ambient Temperature

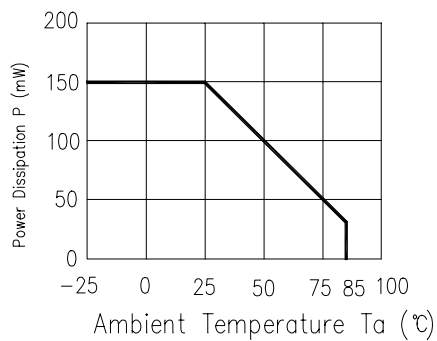


Fig.2 Spectral Sensitivity

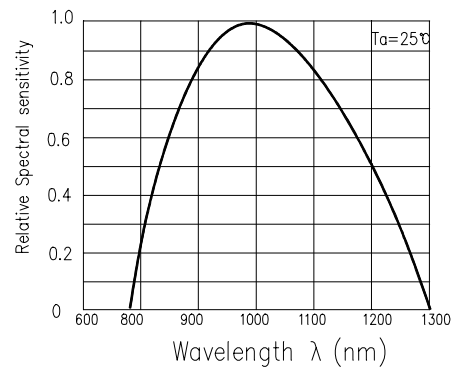


Fig.3 Dark Current vs. Ambient Temperature

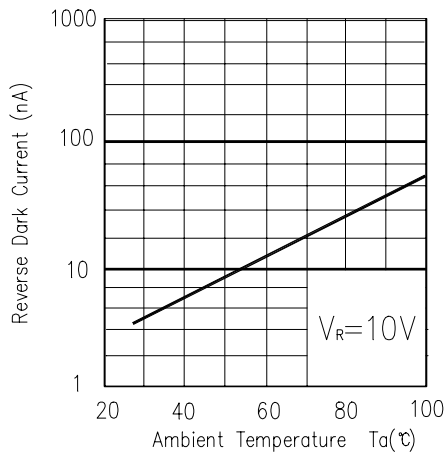


Fig.4 Reverse Light Current vs. E_e

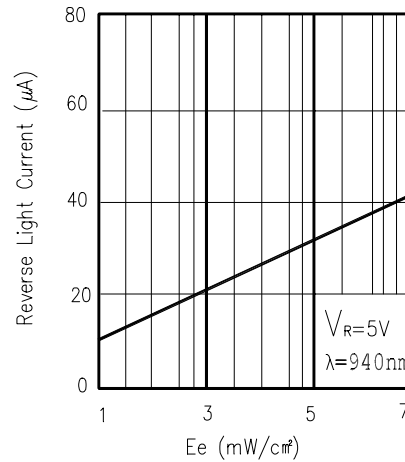


Fig.5 Terminal Capacitance vs. Reverse Voltage

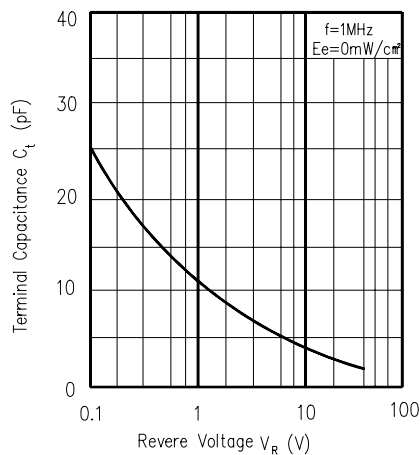
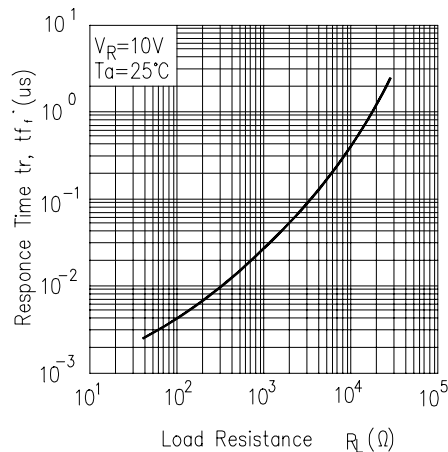


Fig.6 Response Time vs. Load Resistance





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4.8mm Semi-Lens Silicon PIN Photodiode

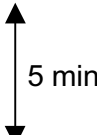
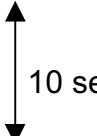
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■ Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level:90%

LTPD:10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP : 260°C ± 5 °C	5 secs	22 pcs	$I_L \leq L_x \times 0.8$ L :Lower specification limit	0/1
2	Temperature Cycle	H : +85°C 30 mins  L : -55°C 30 mins	50 cycles	22 pcs		0/1
3	Thermal Shock	H : +100°C 5 mins  L : -10°C 5 mins	50 cycles	22 pcs		0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 pcs		0/1
5	Low Temperature Storage	TEMP. : -55°C	1000 hrs	22 pcs		0/1
6	DC Operating Life	$V_R=5V$	1000 hrs	22 pcs		0/1
7	High Temperature / High Humidity	85°C / 85% R.H.	1000 hrs	22 pcs		0/1



4.8mm Semi-Lens Silicon PIN Photodiode

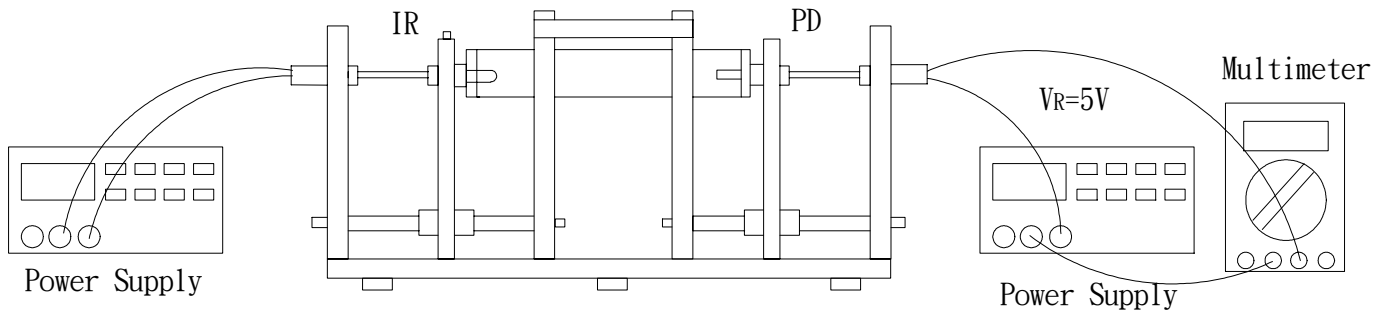
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■ Test Method For Reverse Light Current

Condition: $E_e=5\text{mW}/\text{cm}^2, V_R=5\text{V}$

Test Item: Reverse Light Current)

Unit : μA





DEVICE NUMBER : DPD-043-005

REV : 2.2

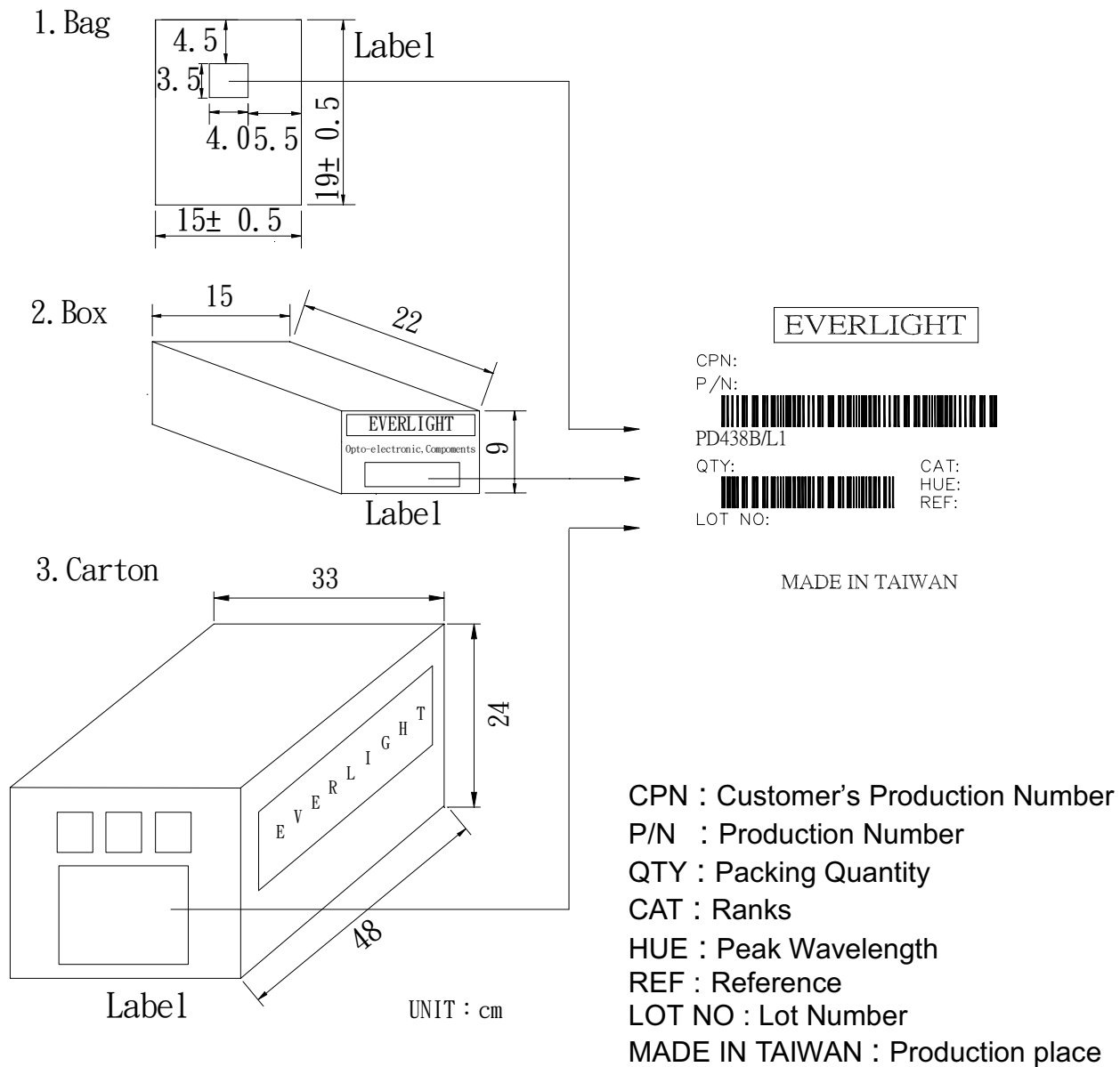
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4.8mm Semi-Lens Silicon PIN Photodiode 2.75 x 5.25mm Silicon PIN Photodiode

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■ Packing Specifications



■ Packing Quantity Specification

- 500 Pcs/1Bag , 10 Bags/1Box
- 10 Boxes/1Carton